

# NL37WZ07

## Triple Buffer with Open Drain Outputs

The NL37WZ07 is a high performance triple buffer with open drain outputs operating from a 1.65 V to 5.5 V supply.

The internal circuit is composed of multiple stages, including an open drain output which provides the capability to set output switching level. This allows the NL37WZ07 to be used to interface 5 V circuits to circuits of any voltage between V<sub>CC</sub> and 7 V using an external resistor and power supply.

### Features

- Extremely High Speed: t<sub>PD</sub> 2.5 ns (typical) at V<sub>CC</sub> = 5 V
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- Overtoltage Tolerant Inputs
- LVTTL Compatible – Interface Capability with 5 V TTL Logic with V<sub>CC</sub> = 3 V
- LVCMS Compatible
- 24 mA Output Sink Capability @ 3.0 V
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 72
- Pb-Free Package is Available

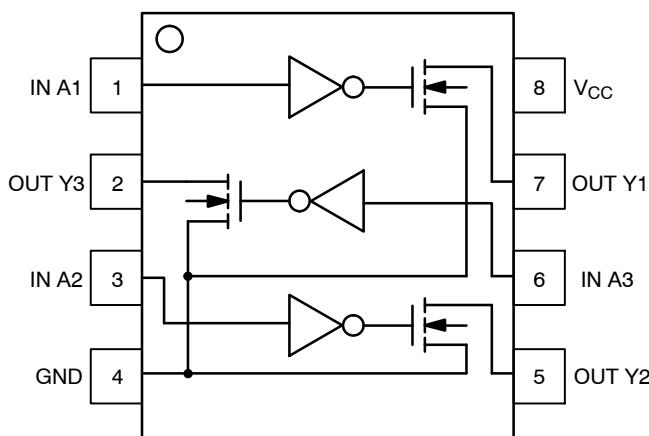


Figure 1. Pinout

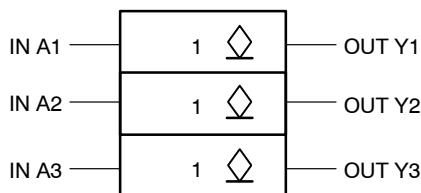
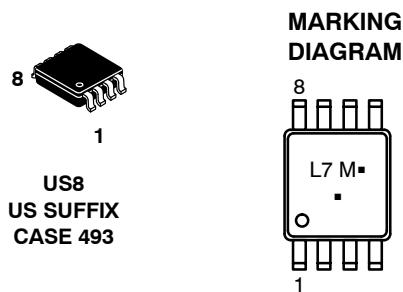


Figure 2. Logic Symbol



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L7 = Device Code  
M = Date Code\*  
- = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

### PIN ASSIGNMENT

1	IN A1
2	OUT Y3
3	IN A2
4	GND
5	OUT Y2
6	IN A3
7	OUT Y1
8	V <sub>CC</sub>

### FUNCTION TABLE

A Input	Y Output
L	L
H	Z

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

**MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	−0.5 to +7.0	V
V <sub>I</sub>	DC Input Voltage	−0.5 to +7.0	V
V <sub>O</sub>	DC Output Voltage	−0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current V <sub>I</sub> < GND	−50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>O</sub> < GND	−50	mA
I <sub>O</sub>	DC Output Sink Current	±50	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	−65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T <sub>J</sub>	Junction Temperature under Bias	+150	°C
θ <sub>JA</sub>	Thermal Resistance (Note 1)	250	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	250	mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	>2000 >150 N/A	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
2. Tested to EIA/JESD22-A114-A.
3. Tested to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage Operating Data Retention Only	1.65 1.5	5.5 5.5	V
V <sub>I</sub>	Input Voltage (Note 5)	0	5.5	V
V <sub>O</sub>	Output Voltage (HIGH or LOW State)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Free-Air Temperature	−55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate V <sub>CC</sub> = 2.5 V ± 0.2 V V <sub>CC</sub> = 3.0 V ± 0.3 V V <sub>CC</sub> = 5.0 V ± 0.5 V	0 0 0	20 10 5	ns/V

5. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.7 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.7 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
I <sub>LKG</sub>	Z-State Output Leakage Current	V <sub>IN</sub> = V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	1.65 to 5.5			± 5.0		± 10.0	µA
V <sub>OL</sub>	Low-Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 µA	1.65 to 5.5		0.0	0.1		0.1	V
		I <sub>OL</sub> = 4 mA	1.65		0.08	0.24		0.24	
		I <sub>OL</sub> = 8 mA	2.3		0.20	0.3		0.3	
		I <sub>OL</sub> = 12 mA	2.7		0.22	0.4		0.4	
		I <sub>OL</sub> = 16 mA	3.0		0.28	0.4		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.38	0.55		0.55	
		I <sub>OL</sub> = 32 mA	4.5		0.42	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> or V <sub>OUT</sub> = V <sub>CC</sub> or GND	0 to 5.5			± 0.1		± 1.0	µA
I <sub>OFF</sub>	Power Off-Output Leakage Current	V <sub>OUT</sub> = 5.5 V	0			1		10	µA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5			1		10	µA

AC ELECTRICAL CHARACTERISTICS t<sub>R</sub> = t<sub>F</sub> = 2.5 ns; C<sub>L</sub> = 50 pF; R<sub>L</sub> = 500 Ω

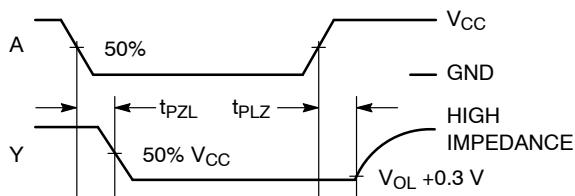
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t <sub>PZL</sub>	Propagation Delay (Figure 3 and 4)	R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	1.8 ± 0.15			7.8		7.8	ns
		R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	2.5 ± 0.2	1.2	3.7	5.8	1.2	6.4	
		R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	3.3 ± 0.3	0.8	2.9	4.4	0.8	4.8	
		R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	5.0 ± 0.5	0.5	2.3	3.5	0.5	3.9	
t <sub>PLZ</sub>	Propagation Delay (Figure 3 and 4)	R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	1.8 ± 0.15			7.8		7.8	ns
		R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	2.5 ± 0.2	1.2	2.8	5.8	1.2	6.4	
		R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	3.3 ± 0.3	0.8	2.1	4.4	0.8	4.8	
		R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	5.0 ± 0.5	0.5	1.4	3.5	0.5	3.9	

## CAPACITIVE CHARACTERISTICS

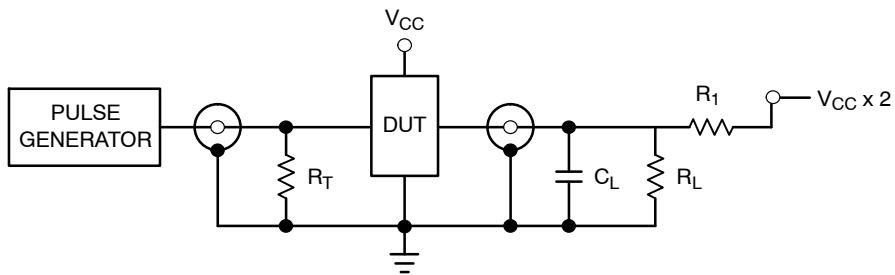
Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	2.5	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	4.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	4.0	pF

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# NL37WZ07



**Figure 3. Switching Waveforms**



$R_T = Z_{OUT}$  of pulse generator (typically 50 Ω)

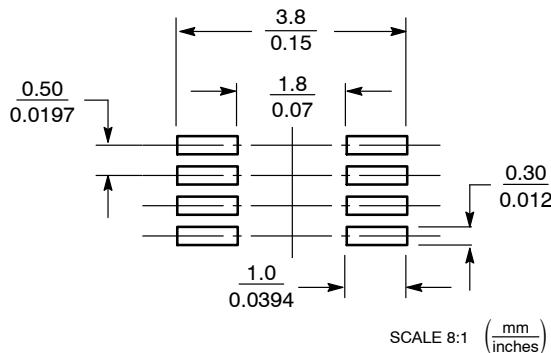
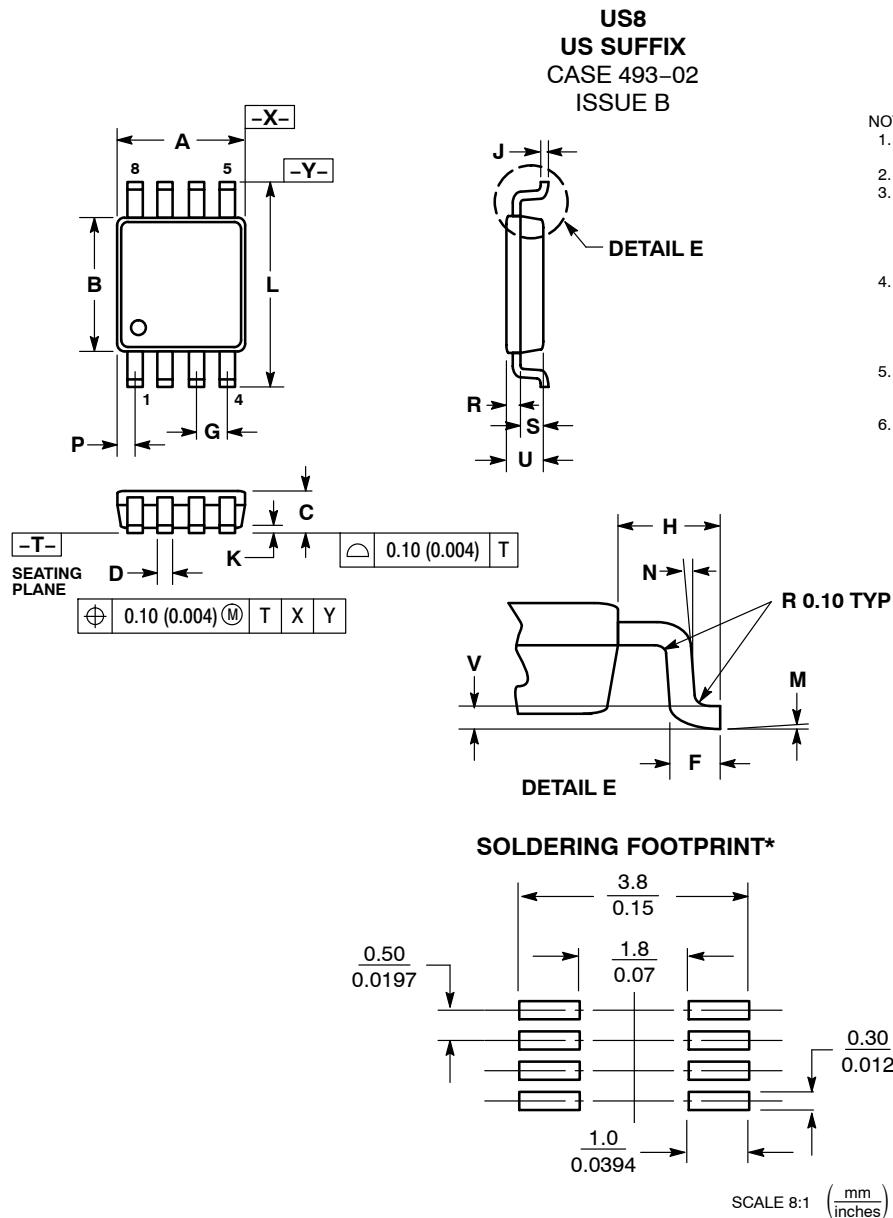
**Figure 4. Test Circuit**

## DEVICE ORDERING INFORMATION

Device Order Number	Package Type	Tape and Reel Size <sup>†</sup>
NL37WZ07US	US8	178 mm (7"), 3000 Units / Tape & Reel
NL37WZ07USG	US8 (Pb-Free)	178 mm (7"), 3000 Units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## PACKAGE DIMENSIONS



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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